



AZ1117I

LOW DROPOUT LINEAR REGULATOR WITH INDUSTRIAL TEMPERATURE RANGE

Description

The DIODES™ AZ1117I is a low dropout three-terminal regulator optimized for a low voltage where transient response and minimum input voltage are critical. The device provides current-limit and thermal-shutdown features. Its circuit includes a trimmed bandgap reference to assure an output voltage accuracy of within ±1%. Onchip thermal shutdown provides protection against a combination of high current and ambient temperature that may create excessive junction temperature.

The AZ1117I is available in 1.2V, 1.5V, 1.8V, 2.5V, 3.3V, and 5.0V fixed output voltage versions and an ADJ output voltage version. The fixed versions integrate the adjust resistors. It is also available in an adjustable version which can set the output voltage with two external resistors.

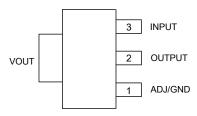
The AZ1117I is available in the industry-standard SOT223 and TO252-2 packages.

Features

- Current Limit: 1.35A (Typ)
- Output Noise from 10Hz to 10KHz: 0.003% of Vout
- PSRR at I_{OUT} = 300mA and f = 120Hz: 70dB
- Output Voltage Accuracy: ±1% (Except 1.2V Version)
- On-chip Thermal Shutdown
- Maximum Quiescent Current: IQMAX = 6mA
- Compatible with Low ESR Ceramic Capacitor
- Operation Junction Temperature: -40°C to +125°C
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/104/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please contact us or your local Diodes representative. https://www.diodes.com/quality/product-definitions/

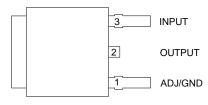
Pin Assignments

(Top View)



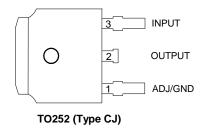
SOT223

(Top View)



TO252-2

(Top View)



Applications

- USB devices
- Add-on cards
- **DVD** players
- PC motherboards

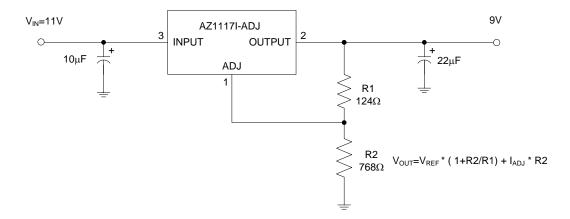
Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.

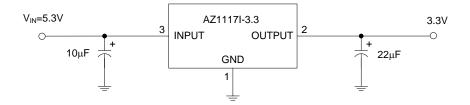
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

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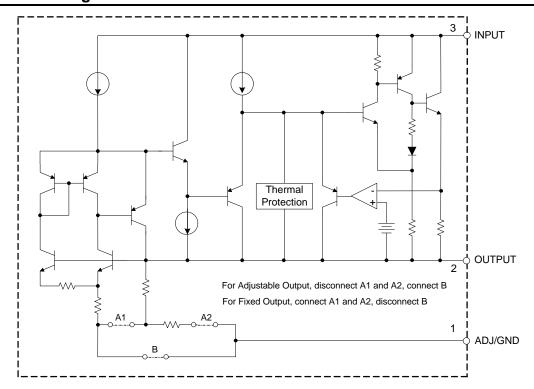
Typical Applications Circuit (Note 4)





Note: 4. The AZ1117I is compatible with low ESR ceramic capacitor. The ESR of the output capacitors must be less than 20Ω. A minimum of 10μF output capacitor is required.

Functional Block Diagram





Absolute Maximum Ratings (Note 5) (@T_A = +25°C, unless otherwise specified.)

Symbol	Parameter	Ratin	Unit		
V_{IN}	Input Voltage	18	}	V	
TJ	Operating Junction Temperature Range	+15	0	°C	
T _{STG}	Storage Temperature Range	-65 to +150		°C	
θ_{JA}	Thermal Resistance (Without Heatsink)	SOT223	125	°C/W	
OJA	Thermal resistance (without reatsink)	TO252-2	100]	
$\theta_{ m JA}$	Thermal Resistance (With Heatsink) (Note 6)	SOT223	100	°C/W	
OJA	Thermal Resistance (William leatering (Note 6)	TO252-2	70	0, **	
T _{LEAD}	Lead Temperature (Soldering, 10sec)	+260		°C	

Notes:

Recommended Operating Conditions (@T_A = +25°C, unless otherwise specified.)

Symbol	Parameter	Min	Max	Unit
V _{IN}	Input Voltage	_	15	V
T_J	Operating Junction Temperature Range	-40	+125	°C

Electrical Characteristics AZ1117I-ADJ

(Operating Conditions: $V_{IN} = V_{OUT} + 2V$, $I_{OUT} = 10$ mA, $T_J = +25$ °C, unless otherwise specified. (P ≤ maximum power dissipation). Limits appearing in **Boldface** type apply over the entire junction temperature range for operation, -40°C to +125°C.)

Symbol	Parameter	Con	ditions	Min	Тур	Max	Unit
\/	Reference Voltage	151/21/11	: 10\/	1.238	1.250	1.262	V
V_{REF}	Reference voltage	1.5V ≤ V _{IN} -V _{OUT} ≤	1.30 = 0 0-000 = 100		1.250	1.275	٧
V _{RLINE}	Line Regulation	1.5V ≤ V _{IN} -V _{OUT} ≤ 10V		_	0.001	0.1	%
VRLINE	Line Regulation	1.5V \(\frac{1}{2}\) VIN-VOUI \(\frac{1}{2}\)	\$ 10V	_	_	0.2	/0
V_{RLOAD}	Load Regulation	$V_{IN} = V_{OUT} + 2V$	$1mA \le I_{OUT} \le 1A$	_	0.4	1.0	%
V	Dropout Voltage	$\Delta V_{REF} = 1\%$,	SOT223	_	1.2	1.3	V
V_{DROP}	Diopout voltage	$I_{OUT} = 0.8A$	TO252-2	_	1.3	1.4	V
I _{LIMIT}	Current Limit	_	_		1.35	_	Α
_	Adjust Pin Current	_		_	60	120	μA
_	Adjust Pin Current Change	$1.5 \le (V_{IN} - V_{OUT}) \le 10V$		_	0.2	5	μΑ
_	Minimum Load Current	1.5 ≤ (V _{IN} -V _{OUT}) ≤	≤ 10V	_	1.7	5	mA
PSRR	Ripple Rejection	$f = 120Hz$, $C_{OUT} = (V_{IN}-V_{OUT}) = 3V$,	•	_	70	_	dB
_	Temperature Stability	_		_	0.5	_	%
_	RMS Output Noise (% of V _{OUT})	T _A = +25°C, 10Hz	z ≤ f ≤ 10KHz	_	0.003	_	%
_	Thermal Shutdown	Junction Tempera	ature	_	+160	_	°C
_	Thermal Shutdown Hysteresis	_		_	+16	_	°C
	The second Decistors			_		_	
θ _{JC}	Thermal Resistance (Junction to Case)	SOT223	SOT223		15	_	°C/W
	(Gariotion to Gade)	TO252-2		_	10		

^{5.} Stresses greater than those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "Recommended Operating Conditions" is not implied.

Exposure to "Absolute Maximum Ratings" for extended periods may affect device reliability.

Exposure to "Absolute Maximum Ratings" for extended periods may affect device reliability.

6. Chip is soldered to 100mm²(10mm*10mm) copper (top side solder mask) on 2oz.2 layers FR-4 PCB with 8*0.5mm vias.



Electrical Characteristics AZ1117I-1.2

(Operating Conditions: $V_{IN} \le 10V$, $I_{OUT} = 10mA$, $T_J = +25^{\circ}C$, unless otherwise specified. (P \le maximum power dissipation). Limits appearing in **Boldface** type apply over the entire junction temperature range for operation, -40°C to +125°C.)

Symbol	Parameter	Con	ditions	Min	Тур	Max	Unit
V	Output Voltage	1 F\/ < \/\/ «	< 10\/	1.176	1.2	1.224	V
Vout	Output Voltage	1.5V ≥ VIN-VOUT ≥	1.5V ≤ V _{IN} -V _{OUT} ≤ 10V		1.2	1.248	V
V	Line Regulation	1.5V ≤ V _{IN} -V _{OUT} ≤ 10V		_	0.5	6	mV
V_{RLINE}	Line Regulation	1.5V \(\text{VIN-VOUT}\)	\$ 10V	_	1	10	IIIV
V_{RLOAD}	Load Regulation	$V_{IN} = V_{OUT}+2V$	$1mA \le I_{OUT} \le 1A$	_	2	15	mV
\/	Dropout Voltage	$\Delta V_{OUT} = 1\%$,	SOT223	_	1.2	1.3	V
V _{DROP}	Dropout Voltage	$I_{OUT} = 0.8A$	TO252-2	_	1.3	1.4	V
I _{LIMIT}	Current Limit	_		1	1.35	_	Α
IQ	Quiescent Current	I _{OUT} = 0	I _{OUT} = 0		4	6	mA
PSRR	Ripple Rejection	f = 120Hz, C _{OUT} =	$f = 120Hz, C_{OUT} = 22\mu F$ (V _{IN} -V _{OUT}) = 3V, I _{OUT} = 300mA		70	_	dB
FORK	Ripple Rejection	$(V_{IN}-V_{OUT})=3V,$					
	Temperature Stability	_		_	0.5		%
	RMS Output Noise (% of V _{OUT})	$T_A = +25$ °C, 10Hz	z ≤ f ≤ 10KHz	_	0.003	_	%
	Thermal Shutdown	Junction Tempera	ature	_	+160	_	°C
_	Thermal Shutdown Hysteresis	_		_	+16	_	°C
θ_{JC}	Thermal Resistance (Junction to Case)	SOT223			15		°C/W
	(Junction to Case)	TO252-2		_	10	_	

Electrical Characteristics AZ1117I-1.5

(Operating Conditions: $V_{IN} \le 10V$, $I_{OUT} = 10mA$, $T_J = +25^{\circ}C$, unless otherwise specified. (P \le maximum power dissipation). Limits appearing in **Boldface** type apply over the entire junction temperature range for operation, -40°C to +125°C.)

Symbol	Parameter	Con	ditions	Min	Тур	Max	Unit
V	Output Voltage	451/41/11	< 40)/	1.485	1.5	1.515	V
V _{OUT}	Output Voltage	$1.5V \le V_{\text{IN}} - V_{\text{OUT}} \le 10V$		1.47	1.5	1.53	V
	Line Regulation	151/21/11	< 10\/	_	0.5	6	mV
V_{RLINE}	Line Regulation	1.5V ≤ V _{IN} -V _{OUT} ≤	≤ IUV	_	_	10	IIIV
V_{RLOAD}	Load Regulation	$V_{IN} = V_{OUT} + 2V$	$1mA \le I_{OUT} \le 1A$	_	2	15	mV
V	Drangut Voltage	$\Delta V_{OUT} = 1\%$,	SOT223	_	1.2	1.3	V
V _{DROP}	Dropout Voltage	$I_{OUT} = 0.8A$	TO252-2	_	1.3	1.4	V
I _{LIMIT}	Current Limit	_		1	1.35	_	Α
ΙQ	Quiescent Current	I _{OUT} = 0	I _{OUT} = 0		4	6	mA
PSRR	Ripple Rejection	$f = 120Hz, C_{OUT} = (V_{IN}-V_{OUT}) = 3V,$	•	_	70	_	dB
_	Temperature Stability	_		_	0.5	_	%
_	RMS Output Noise (% of V _{OUT})	T _A = +25°C, 10Hz	z ≤ f ≤ 10KHz	_	0.003	_	%
_	Thermal Shutdown	Junction Tempera	ature	_	+160	_	°C
_	Thermal Shutdown Hysteresis	<u> </u>		_	+16	_	°C
	Thermal Resistance	207222	_	_	4.5	_	
θ_{JC}	(Junction to Case)	SO1223	SOT223		15	_	°C/W
	(Sansaon to Sass)	TO252-2		I —	10	_	



Electrical Characteristics AZ1117I-1.8

(Operating Conditions: $V_{IN} \le 10V$, $I_{OUT} = 10mA$, $T_J = +25^{\circ}C$, unless otherwise specified. (P \le maximum power dissipation). Limits appearing in **Boldface** type apply over the entire junction temperature range for operation, -40°C to +125°C.)

Symbol	Parameter	Con	ditions	Min	Тур	Max	Unit
\/	Output Voltage	1 5\/ < \/\/	: 10\/	1.782	1.8	1.818	V
Vouт	Output Voltage	1.5V ≥ VIN-VOUT ≥	$1.5V \le V_{IN}-V_{OUT} \le 10V$		1.8	1.836	V
\/	Line Demulation	1 5 1 6 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1	1.5V ≤ V _{IN} -V _{OUT} ≤ 10V		0.5	6	mV
V _{RLINE}	Line Regulation	1.5V \(\text{VIN-VOUT}\)	: 10 V	_		10	IIIV
V _{RLOAD}	Load Regulation	V _{IN} = V _{OUT} +2V	1mA ≤ I _{OUT} ≤ 1A	_	2	15	mV
	Drangut Voltage	$\Delta V_{OUT} = 1\%$,	SOT223	_	1.2	1.3	V
V _{DROP}	Dropout Voltage	$I_{OUT} = 0.8A$	TO252-2	_	1.3	1.4	V
I _{LIMIT}	Current Limit	_	_		1.35	_	Α
IQ	Quiescent Current	I _{OUT} = 0	I _{OUT} = 0		4	6	mA
PSRR	Ripple Rejection	$f = 120$ Hz, $C_{OUT} = 22\mu F$ ($V_{IN}-V_{OUT}) = 3V$, $I_{OUT} = 300$ mA			70	_	dB
1 SIXIX	Tripple Trejection				70		
_	Temperature Stability	_		_	0.5	_	%
_	RMS Output Noise (% of V _{OUT})	$T_A = +25^{\circ}C$, 10Hz	: ≤ f ≤ 10KHz	_	0.003	_	%
_	Thermal Shutdown	Junction Tempera	Junction Temperature		+160	_	°C
_	Thermal Shutdown Hysteresis	_		_	+16	_	°C
				_		_	
θ_{JC}	Thermal Resistance (Junction to Case)	SOT223	SOT223		15	_	°C/W
	(Junetion to Gase)	TO252-2		_	10	_	

Electrical Characteristics AZ1117I-2.5

(Operating Conditions: $V_{IN} \le 10V$, $I_{OUT} = 10mA$, $T_J = +25^{\circ}C$, unless otherwise specified. (P \le maximum power dissipation). Limits appearing in **Boldface** type apply over the entire junction temperature range for operation, -40°C to +125°C.)

Symbol	Parameter	Con	ditions	Min	Тур	Max	Unit
	Output Voltage	451/21/11	(40)/	2.475	2.5	2.525	V
V_{OUT}	Output Voltage	1.5V \(\text{VIN-VOUT}\)	1.5V ≤ V _{IN} -V _{OUT} ≤ 10V		2.5	2.545	V
\/	Line Regulation	451/21/11	(40)/	_	0.5	6	mV
V_{RLINE}	Line Regulation	1.5V ≤ V _{IN} -V _{OUT} ≤	≤ 10V	_	_	10	IIIV
V_{RLOAD}	Load Regulation	V _{IN} = V _{OUT} +2V	1mA ≤ I _{OUT} ≤ 1A	_	2	15	mV
\/	Dropout Voltage	$\Delta V_{OUT} = 1\%$,	SOT223	_	1.2	1.3	V
V_{DROP}	Dropout Voltage	$I_{OUT} = 0.8A$	TO252-2	_	1.3	1.4	V
I _{LIMIT}	Current Limit	_	<u> </u>		1.35	_	Α
ΙQ	Quiescent Current	I _{OUT} = 0	I _{OUT} = 0		4	6	mA
PSRR	Ripple Rejection	$f = 120Hz, C_{OUT} = (V_{IN}-V_{OUT}) = 3V,$		_	70	_	dB
_	Temperature Stability	_		_	0.5	_	%
_	RMS Output Noise (% of V _{OUT})	T _A = +25°C, 10Hz	z ≤ f ≤ 10KHz	_	0.003	_	%
_	Thermal Shutdown	Junction Tempera	ature	_	+160	_	°C
_	Thermal Shutdown Hysteresis	_		_	+16	_	°C
	Thermal Desistance	207222		_		_	
θ_{JC}	Thermal Resistance (Junction to Case)	SOT223	SOT223		15		°C/W
	(Gariotto Gase)	TO252-2	·	_	10	_	



Electrical Characteristics AZ1117I-3.3

(Operating Conditions: $V_{IN} \le 10V$, $I_{OUT} = 10mA$, $T_J = +25^{\circ}C$, unless otherwise specified. (P \le maximum power dissipation). Limits appearing in **Boldface** type apply over the entire junction temperature range for operation, -40°C to +125°C.)

Symbol	Parameter	Cor	nditions	Min	Тур	Max	Unit
V	Output Voltage	1.51/<./	-< 10\/	3.267	3.3	3.333	V
Vouт	Output Voltage	1.5V ≤ V _{IN} -V _{OUT} ≤ 10V		3.235	3.3	3.365	V
V	Line Regulation 1.5V ≤ V _{IN} -V _{OUT} ≤ 10V	4.51/ 51/ 1/ 5401/		_	0.5	6	mV
V_{RLINE}	Line Regulation	1.5V \(\frac{1}{2}\) VIN-VOU	[≥ 10 V	_	_	10	IIIV
V_{RLOAD}	Load Regulation	$V_{IN} = V_{OUT} + 2V$	$1mA \le I_{OUT} \le 1A$	_	2	15	mV
V	Dropout Voltage	$\Delta V_{OUT} = 1\%$,	SOT223	_	1.2	1.3	V
V_{DROP}	Diopout voitage	$I_{OUT} = 0.8A$	TO252-2	_	1.3	1.4	V
I _{LIMIT}	Current Limit	_	_		1.35	_	Α
IQ	Quiescent Current	I _{OUT} = 0		_	4	6	mA
PSRR	Ripple Rejection	$f = 120Hz, C_{OUT} = 22\mu F$ $(V_{IN}-V_{OUT}) = 3V, I_{OUT} = 300mA$			70		dB
FORK	Rippie Rejection				70		
_	Temperature Stability	_		_	0.5	_	%
_	RMS Output Noise (% of V _{OUT})	$T_A = +25^{\circ}C$, 10	Hz ≤ f ≤ 10KHz	_	0.003	_	%
_	Thermal Shutdown	Junction Tempe	erature	_	+160	_	°C
_	Thermal Shutdown Hysteresis	_		_	+16	_	°C
	The arrest Designation of			_		_	
θ_{JC}	Thermal Resistance (Junction to Case)	SOT223	SOT223		15	_	°C/W
	(dunotion to dase)	TO252-2		_	10	_	

Electrical Characteristics AZ1117I-5.0

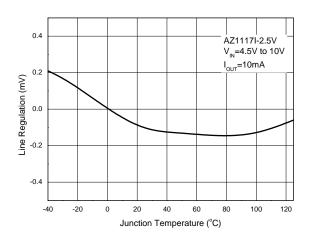
(Operating Conditions: $V_{IN} \le 10V$, $I_{OUT} = 10mA$, $T_J = +25^{\circ}C$, unless otherwise specified. (P \le maximum power dissipation). Limits appearing in **Boldface** type apply over the entire junction temperature range for operation, -40°C to +125°C.)

Symbol	Parameter	Con	ditions	Min	Тур	Max	Unit
	Output Valtage	451/41/1/	40)/	4.950	5.0	5.050	V
V_{OUT}	Output Voltage	1.5V ≤ V _{IN} -V _{OUT} \$	$1.5V \le V_{\text{IN}} - V_{\text{OUT}} \le 10V$		5.0	5.100	V
	Line Degulation	457777	(40)/	_	0.5	6	mV
V_{RLINE}	Line Regulation	1.5V ≤ V _{IN} -V _{OUT} ≤	≤ 10V	_	_	10	IIIV
V_{RLOAD}	Load Regulation	V _{IN} = V _{OUT} +2V	1mA ≤ I _{OUT} ≤ 1A	_	2	15	mV
	Dropout Voltage	$\Delta V_{OUT} = 1\%$,	SOT223	_	1.2	1.3	V
V _{DROP}	Dropout Voltage	$I_{OUT} = 0.8A$	TO252-2	_	1.3	1.4	V
I _{LIMIT}	Current Limit	_	_		1.35	_	Α
IQ	Quiescent Current	I _{OUT} = 0	I _{OUT} = 0		4	6	mA
PSRR	Ripple Rejection	f = 120Hz, C _{OUT} =	= 22µF	_	70	_	dB
	Tappie Tojecaen	$(V_{IN}-V_{OUT})=3V,$	$(V_{IN}-V_{OUT}) = 3V, I_{OUT} = 300mA$		70		UD
_	Temperature Stability	_		_	0.5	_	%
_	RMS Output Noise (% of V _{OUT})	$T_A = +25^{\circ}C$, 10Hz	z ≤ f ≤ 10KHz	_	0.003	_	%
_	Thermal Shutdown	Junction Tempera	Junction Temperature		+160	_	°C
_	Thermal Shutdown Hysteresis	_	-		+16	_	°C
θ_{JC}	Thermal Resistance	SOT223	SOT223		15	_	°C/W
-30	(Junction to Case)	TO252-2		_	10	_]

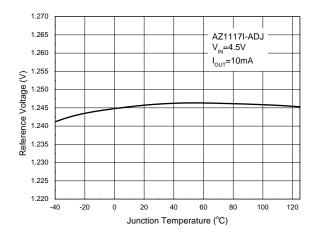


Performance Characteristics

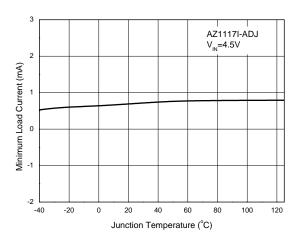
Line Regulation vs. Temperature



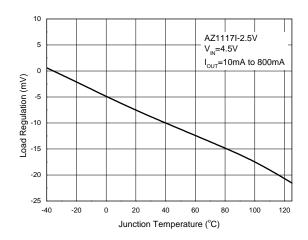
Reference Voltage vs. Temperature



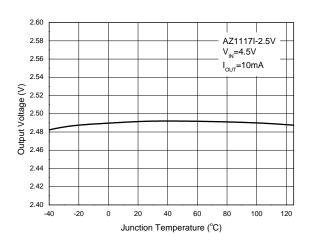
Minimum Load Current vs. Temperature



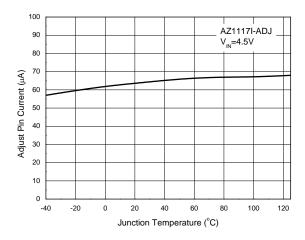
Load Regulation vs. Temperature



Output Voltage vs. Temperature



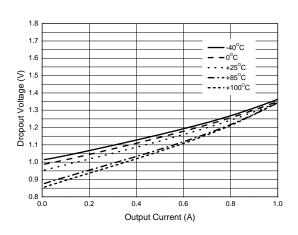
Adjust Pin Current vs. Temperature



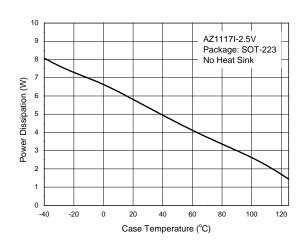


Performance Characteristics (continued)

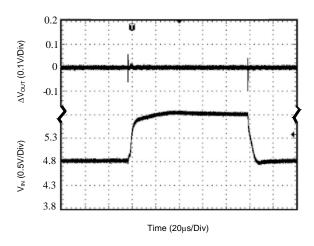
Dropout Voltage vs. Output Current



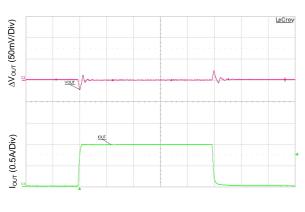
Power Dissipation vs. Temperature



Line Transient Response

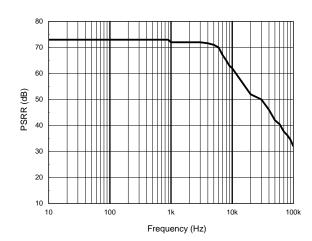


Load Transient Response

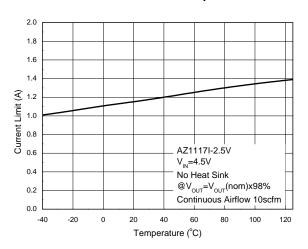


Time (10µs/Div)

PSRR vs. Frequency



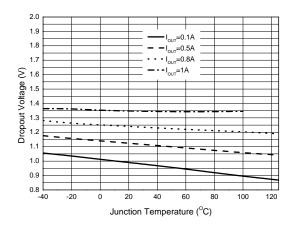
Current Limit vs. Temperature

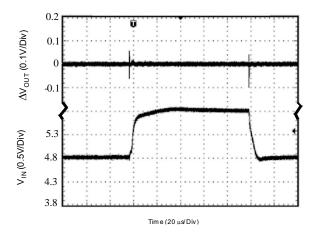


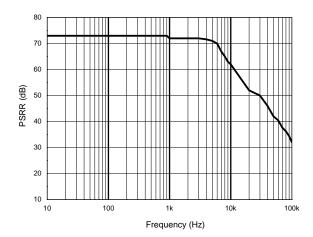


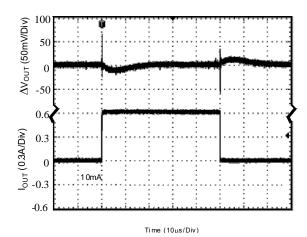
Performance Characteristics (continued)

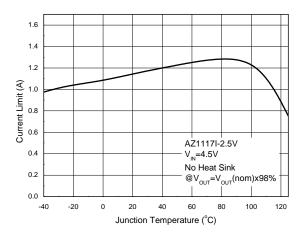
Dropout Voltage vs. Temperature





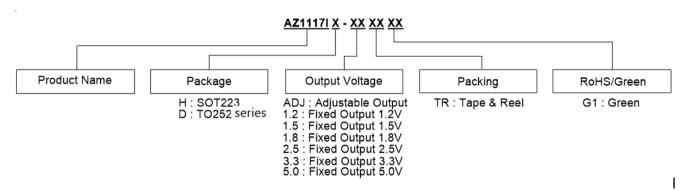








Ordering Information



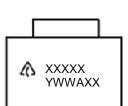
Dankawa	Temperature	Orderable	Maulina ID	Pa	cking
Package	Range	Part Number	Marking ID	Qty.	Carrier
		AZ1117IH-ADJTRG1	GH86J	4000	Tape & Reel
		AZ1117IH-1.2TRG1	GH86K	4000	Tape & Reel
		AZ1117IH-1.5TRG1	GH86L	4000	Tape & Reel
SOT223		AZ1117IH-1.8TRG1	GH86M	4000	Tape & Reel
		AZ1117IH-2.5TRG1 GH86N		4000	Tape & Reel
		AZ1117IH-3.3TRG1	GH86P	4000	Tape & Reel
	409C to 14050C	AZ1117IH-5.0TRG1	GH86Q	4000	Tape & Reel
	-40°C to +125°C	AZ1117ID-ADJTRG1	AZ1117ID-ADJG1	2500	Tape & Reel
		AZ1117ID-1.2TRG1	AZ1117ID-1.2G1	2500	Tape & Reel
		AZ1117ID-1.5TRG1	AZ1117ID-1.5G1	2500	Tape & Reel
TO252-2 TO252 (Type CJ)		AZ1117ID-1.8TRG1	AZ1117ID-1.8G1	2500	Tape & Reel
		AZ1117ID-2.5TRG1	AZ1117ID-2.5G1	2500	Tape & Reel
		AZ1117ID-3.3TRG1	AZ1117ID-3.3G1	2500	Tape & Reel
		AZ1117ID-5.0TRG1	AZ1117ID-5.0G1	2500	Tape & Reel

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Marking Information

(1) SOT223



(Top View)

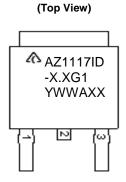
First Line: Logo and Marking ID (See Ordering Information) Second Line: Date Code

Y: Year

WW: Work Week of Molding

A: Assembly House Code XX: 7th and 8th Digits of Batch Number

(2) TO252-2 /TO252 (Type CJ)



First and Second Lines: Logo and Marking ID

(See Ordering Information) Third Line: Date Code

Y: Year

WW: Work Week of Molding

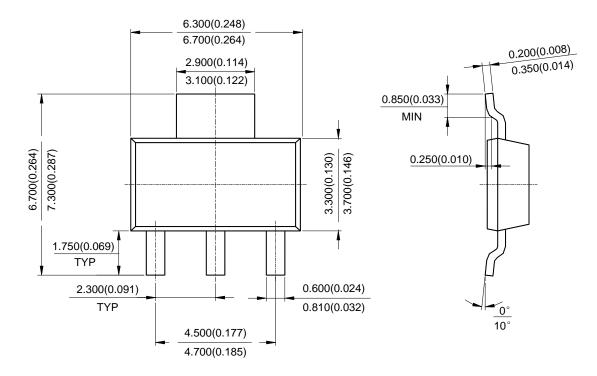
A: Assembly House Code XX: 7th and 8th Digits of Batch Number

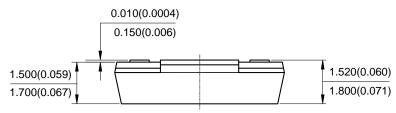


Package Outline Dimensions (All dimensions in mm)

Please see http://www.diodes.com/package-outlines.html for the latest version.

(1) Package Type: SOT223



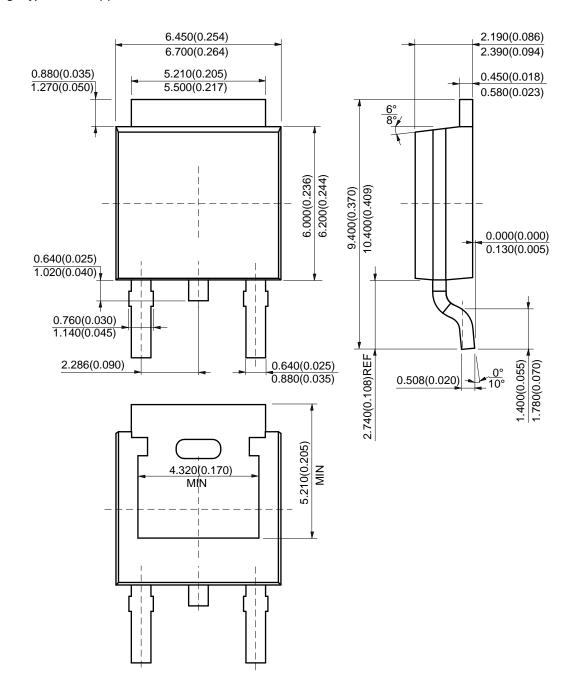




Package Outline Dimensions (All dimensions in mm) (continued)

Please see http://www.diodes.com/package-outlines.html for the latest version.

(2) Package Type: TO252-2 (5)

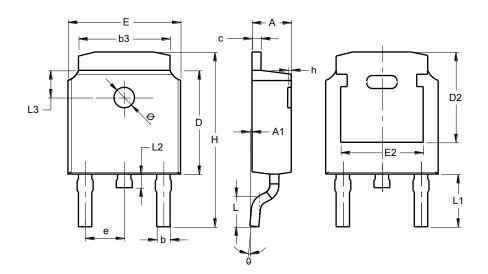




Package Outline Dimensions (All dimensions in mm) (continued)

Please see http://www.diodes.com/package-outlines.html for the latest version.

(3) Package Type: TO252 (Type CJ)



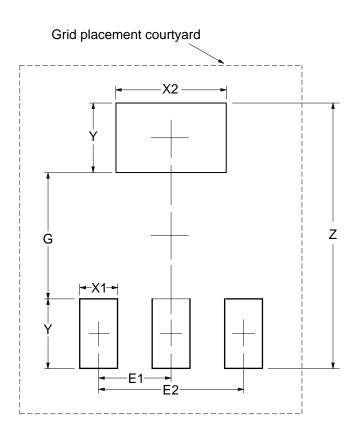
	TC)252					
	_ ` '	oe CJ)					
Dim	Min	Max	Тур				
Α	2.200	2.400					
A 1	0.000	0.127					
b	0.635	0.770					
b3	5.100	5.460					
С	0.460						
D 6.000 6.200							
D2	5	.250 RE	F				
Е	6.500	6.700					
E2	4	.830 RE	F				
е	2.186	2.386					
h	0.000	0.300					
Н	9.712	10.312					
J	1.400	1.700					
L1	2	.900 RE	F				
L2	0.600	1.000					
L3	1.	.600 RE	F				
Ø	1.100	1.300					
θ	0°	8°					
Al	l Dimen	sions in	mm				



Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

(1) Package Type: SOT223



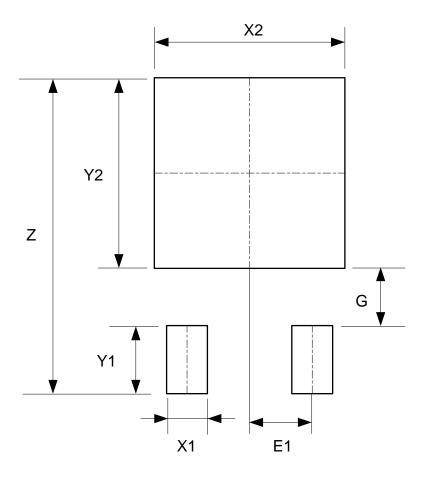
Dimensions	Z	G	X1	X2	Y	E1	E2
	(mm)/(inch)						
Value	8.400/0.331	4.000/0.157	1.200/0.047	3.500/0.138	2.200/0.087	2.300/0.091	4.600/0.181



Suggested Pad Layout (continued)

Please see http://www.diodes.com/package-outlines.html for the latest version.

(2) Package Type: TO252-2 (5) / TO252 (Type CJ)



Dimensions	Z	X1	X2=Y2	Y1	G	E1
	(mm)/(inch)	(mm)/(inch)	(mm)/(inch)	(mm)/(inch)	(mm)/(inch)	(mm)/(inch)
Value	11.600/0.457	1.500/0.059	7.000/0.276	2.500/0.098	2.100/0.083	2.300/0.091

Mechanical Data

- Moisture Sensitivity: Level 3 per J-STD-020
- Terminals: Finish— Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 (3)
- Weight
 - TO-252-2 / TO252 (Type CJ): 0.312 grams (Approximate)
 - SOT-223: 0.116 grams (Approximate)



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